

Vishay Semiconductors

Ultralow V_F Hyperfast Rectifier for Discontinuous Mode PFC, 15 A FRED Pt[®]



TO-220AC

Base

cathode

02

TO-220 FULL-PAK



VS-15ETL06PbF

Anode

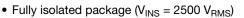
Cathode

VS-15ETL06FPPbF

PRODUCT SUMMARY								
Package	TO-220AC, TO-220FP							
I _{F(AV)}	15 A							
V _R	600 V							
V _F at I _F	1.05 V							
t _{rr} typ.	60 ns							
T _J max.	175 °C							
Diode variation	Single die							

FEATURES

- Hyperfast recovery time
- Benchmark ultralow forward voltage drop
- 175 °C operating junction temperature
- Low leakage current



- UL E78996 pending
- Designed and qualified for industrial level
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

State of the art, ultralow V_F , soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Peak repetitive reverse voltage	V _{RRM}		600	V					
Average rectified forward current	l	T _C = 154 °C	15						
Average rectilied forward current	I _{F(AV)}	T _C = 120 °C (FULL-PAK)	15	A					
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	250	A					
Peak repetitive forward current	I _{FM}		30						
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C					

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
E	V _F	I _F = 15 A	-	0.99	1.05	V			
Forward voltage		I _F = 15 A, T _J = 150 °C	-	0.85	0.92				
Deverse leekeese eurrent		V _R = V _R rated	-	0.1	10				
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	15	120	μΑ			
Junction capacitance	CT	V _R = 600 V	-	20	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH			





 Document Number:
 94004
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 DiodesEurope@vishay.com

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DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ J}$	Α/μs, V _R = 30 V	-	60	120				
	+	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 100$	-	190	270					
	t _{rr}	T _J = 25 °C		-	220	-	ns A			
		T _J = 125 °C		-	320	-				
Deals receiver a surrent	I _{RRM}	T _J = 25 °C	$I_F = 15 A$	-	19	-				
Peak recovery current		T _J = 125 °C	dl _F /dt = 200 A/µs V _B = 390 V	-	26	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C	· · · · · · · · · · · · · · · · · · ·	-	2.2	-				
		T _J = 125 °C		-	4.3	-	μC			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C			
Thermal resistance,	P		-	1.0	1.3				
junction to case (FULL-PAK)	R _{thJC}		-	3.0	3.5				
Thermal resistance, junction to ambient per leg	R _{thJA} Typical socket mount		-	-	70	°C/W			
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-				
Weight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking davias		Case style TO-220AC		15E	15ETL06				
Marking device		Case style TO-220AC FULL-PAK	15ETL06FP						

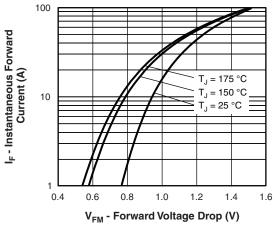
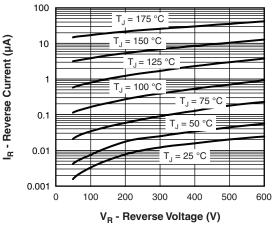
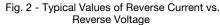


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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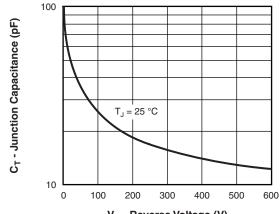




Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

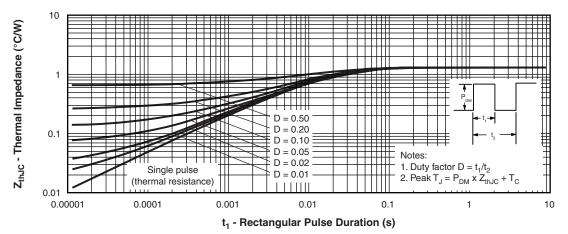
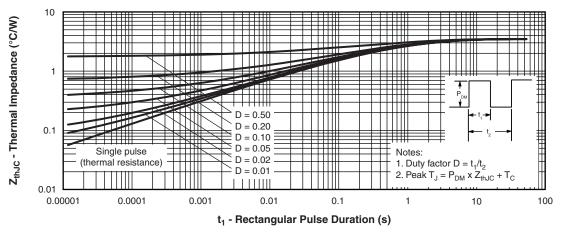
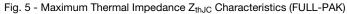


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



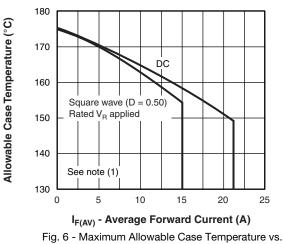


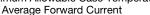
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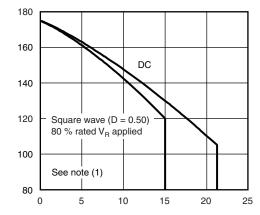
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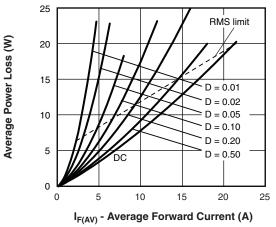


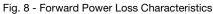


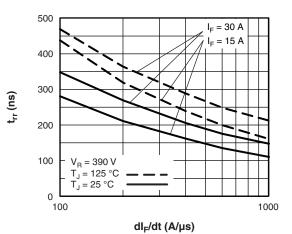


I_{F(AV)} - Average Forward Current (A)

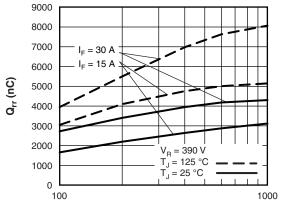
Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)











dl_F/dt (A/μs) Fig. 10 - Typical Stored Charge vs. dl_F/dt

Note

Allowable Case Temperature (°C)

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})} / \mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{8}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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Ultralow V_F Hyperfast Rectifier for Discontinuous Mode PFC, 15 A FRED $Pt^{\$}$

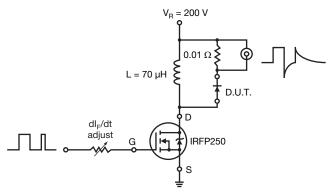
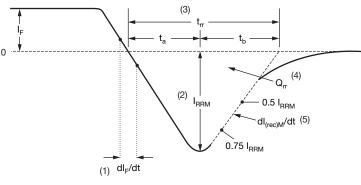


Fig. 11 - Reverse Recovery Parameter Test Circuit



(1) dI_F/dt - rate of change of current through zero crossing

(4) ${\rm Q}_{\rm rr}$ - area under curve defined by ${\rm t}_{\rm rr}$ and ${\rm I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(2) ${\rm I}_{\rm RRM}$ - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

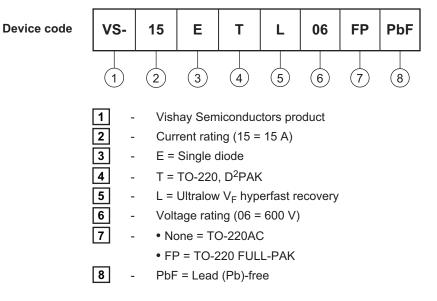
Fig. 12 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS								
Dimensions	TO-220AC	www.vishay.com/doc?95221						
	TO-220AC FULL-PAK	www.vishay.com/doc?95005						
Part marking information	TO-220AC	www.vishay.com/doc?95224						
	TO-220AC FULL-PAK	www.vishay.com/doc?95009						
SPICE model		www.vishay.com/doc?95270						

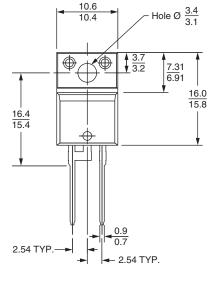
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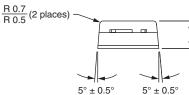
Outline Dimensions

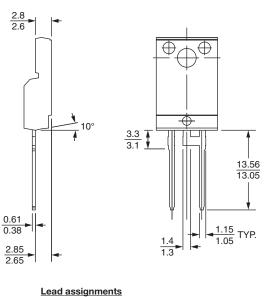
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DIMENSIONS in millimeters



 $\frac{4.8}{4.6}$





<u>Lead assignments</u> <u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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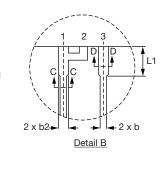
TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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